

RF AMPLIFIER

MODEL *TM3016*

Available as: TM3016, 4 Pin TO-8 (T4)
 TN3016, 4 Pin Surface Mount (SM3)
 FP3016, 4 Pin Flatpack (FP4)
 BX3016, Connectorized Housing (H1)

Features

- Low Noise Figure: <2.3 Typical
- High Gain: 29 dB Typical
- Operating Temp. -55 °C to + 85 °C
- Environmental Screening Available

Specifications

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10-250 MHz	10-250 MHz
Gain (dB)	29	27 Min.
Power @ 1 dB Comp. (dBm)	+16	+14.5
Reverse Isolation (dB)	-44	-42 Max.
VSWR In	<1.5:1	2.0:1 Max.
Out	<1.25:1	2.0:1 Max.
Noise Figure (dB)	<2.3	3.0 Max.
Power Vdc	+15	+15
mA	62	65 Max.

Note: Care should always be taken to effectively ground the case of each unit.

Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point +40 dBm (Typ.)
 Second Order Two Tone Intercept Point +34 dBm (Typ.)
 Third Order Two Tone Intercept Point +28 dBm (Typ.)

Maximum Ratings

Ambient Operating Temperature -55°C to + 100 °C
 Storage Temperature -62°C to + 125 °C
 Case Temperature + 125 °C
 DC Voltage + 18 Volts
 Continuous RF Input Power + 7 dBm
 Short Term RF Input Power 10 Milliwatts (1 Minute Max.)
 Maximum Peak Power 0.1 Watt (3 µsec Max.)

Typical Performance Data

